

# 2MBI150XHA170-50

IGBT Modules

**Power Module (X series)**  
**1700V / 150A / 2-in-1 package**

■ **Features**

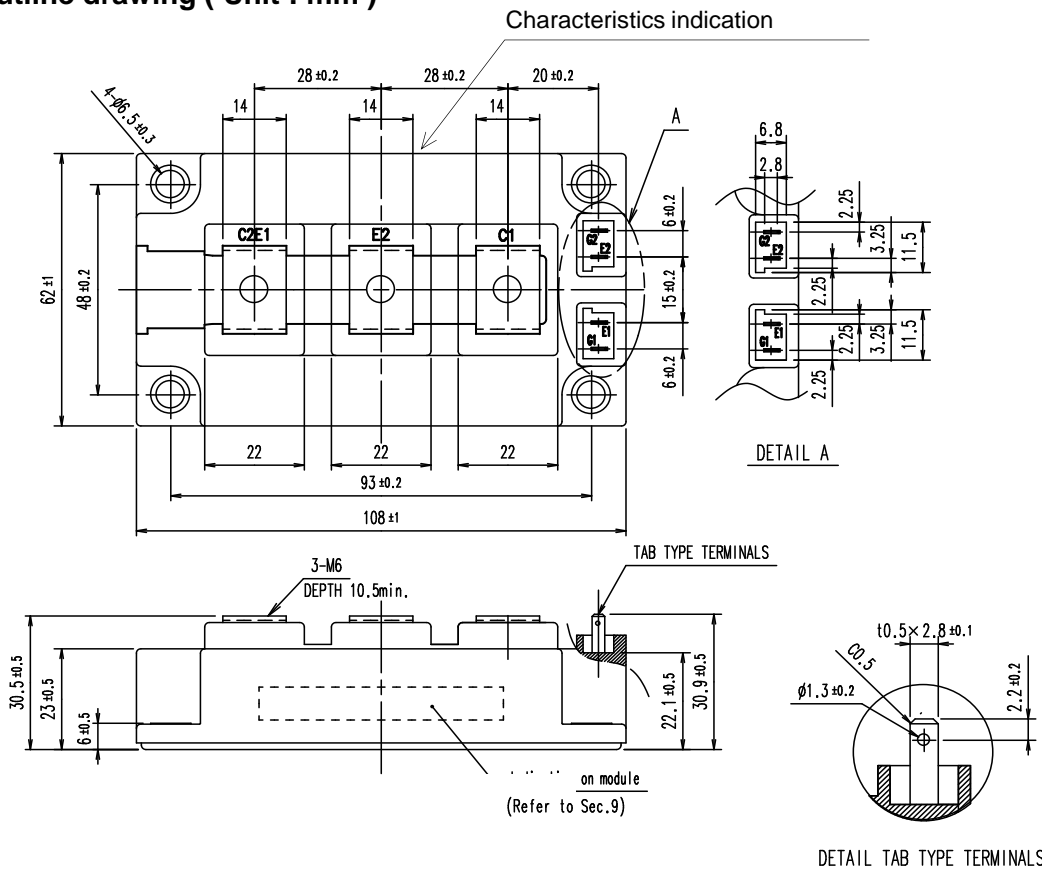
- Low  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

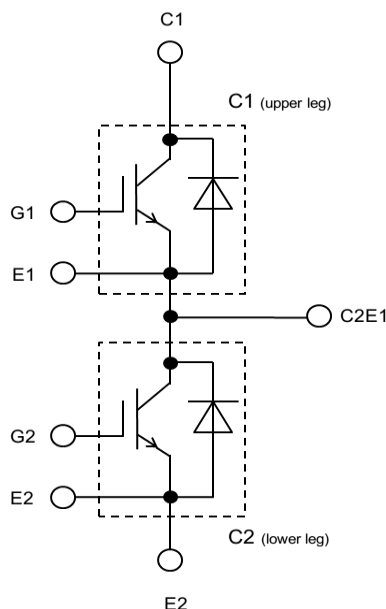


■ **Outline drawing ( Unit : mm )**



Weight: 370 g(typ.)

■ **Equivalent Circuit**



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**■ Absolute Maximum Ratings (at  $T_C=25^\circ\text{C}$  unless otherwise specified)**

Items		Symbols	Conditions	Maximum Ratings	Units
Collector-Emitter voltage, Gate-Emitter short-circuited		$V_{CES}$		1700	V
Gate-Emitter voltage, Collector-Emitter short-circuited		$V_{GES}$		$\pm 20$	V
Collector current		$I_C$	Continuous   $T_C=100^\circ\text{C}$	150	A
Repetitive peak collector current		$I_{CRM}$	1ms	300	
Forward current		$I_F$		150	
Repetitive peak forward current		$I_{FRM}$	1ms	300	
Total power dissipation		$P_{tot}$	1 device	925	W
Virtual junction temperature		$T_{vj}$		175	°C
Operating virtual junction temperature		$T_{vjop}$		175	
Case temperature		$T_C$		125	
Storage temperature		$T_{stg}$		-40 ~ 125	
Isolation voltage	between terminals and copper base (*1)	$V_{isol}$	AC: 1min.	4000	Vrms
Mounting torque of screws to heatsink (*2)		-	M5 or M6	6.0	N·m
Mounting torque of screws to terminals (*2)		-	M5	5.0	

(\*1) All terminals should be connected together during the test.

(\*2) Recommendable Value:           Mounting                           3.0 ~ 6.0 N·m   (M5 or M6)  
   Recommendable Value:        Terminals                       2.5 ~ 5.0 N·m   (M6)

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**5. Electrical characteristics (at  $T_{vj} = 25^\circ\text{C}$  unless otherwise specified)**

	Symbols	Conditions		Characteristics			Units
				min.	typ.	max.	
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1700V$	-	-	100	$\mu\text{A}$	
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 150\text{mA}$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 150A$	$T_{vj}=25^\circ\text{C}$	-	1.70	2.15	V
	$V_{CE(sat)}$ (chip)		$T_{vj}=25^\circ\text{C}$	-	1.60	2.05	
			$T_{vj}=125^\circ\text{C}$	-	2.00	-	
			$T_{vj}=150^\circ\text{C}$	-	2.10	-	
			$T_{vj}=175^\circ\text{C}$	-	2.20	-	
Internal Gate resistance	$r_g$	-	-	6.25	-	$\Omega$	
Capacitance	$C_{ies}$	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	-	-	21	-	nF
	$C_{oes}$		-	-	0.6	-	
	$C_{res}$		-	-	0.13	-	
Gate charge	$Q_G$	$V_{CC} = 900V, I_C = 150A$ $V_{GE} = -15 \rightarrow +15V$	-	1300	-	nC	
Forward voltage	$V_F$ (terminal)	$V_{GE} = 0V$ $I_F = 150A$	$T_{vj}=25^\circ\text{C}$	-	1.80	2.25	V
	$V_F$ (chip)		$T_{vj}=25^\circ\text{C}$	-	1.70	2.15	
			$T_{vj}=125^\circ\text{C}$	-	1.80	-	
			$T_{vj}=150^\circ\text{C}$	-	1.85	-	
			$T_{vj}=175^\circ\text{C}$	-	1.80	-	
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 900V$ $I_C, I_F = 150A$ $V_{GE} = \pm 15V$ $R_G = 1\Omega$ $L_S = 30\text{ nH}$	$T_{vj}=25^\circ\text{C}$	-	370	-	ns
			$T_{vj}=125^\circ\text{C}$	-	445	-	
			$T_{vj}=150^\circ\text{C}$	-	395	-	
			$T_{vj}=175^\circ\text{C}$	-	395	-	
	$t_r$		$T_{vj}=25^\circ\text{C}$	-	90	-	
			$T_{vj}=125^\circ\text{C}$	-	65	-	
			$T_{vj}=150^\circ\text{C}$	-	70	-	
			$T_{vj}=175^\circ\text{C}$	-	130	-	
	$t_{d(off)}$		$T_{vj}=25^\circ\text{C}$	-	425	-	
			$T_{vj}=125^\circ\text{C}$	-	480	-	
			$T_{vj}=150^\circ\text{C}$	-	495	-	
			$T_{vj}=175^\circ\text{C}$	-	505	-	
	$t_f$		$T_{vj}=25^\circ\text{C}$	-	495	-	
			$T_{vj}=125^\circ\text{C}$	-	610	-	
			$T_{vj}=150^\circ\text{C}$	-	645	-	
			$T_{vj}=175^\circ\text{C}$	-	635	-	
Reverse recovery time	$t_{rr}$	$T_{vj}=25^\circ\text{C}$	-	200	-		
		$T_{vj}=125^\circ\text{C}$	-	360	-		
		$T_{vj}=150^\circ\text{C}$	-	400	-		
		$T_{vj}=175^\circ\text{C}$	-	465	-		

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■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Switching loss (per pulse)	$E_{on}$	$V_{CC} = 900\text{V}$ $I_C, I_F = 150\text{A}$ $V_{GE} = \pm 15\text{V}$ $R_G = 1\ \Omega$ $L_S = 30\ \text{nH}$	$T_{vj}=25^{\circ}\text{C}$	-	37.5	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	48.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	52.5	-	
			$T_{vj}=175^{\circ}\text{C}$	-	55.8	-	
	$E_{off}$		$T_{vj}=25^{\circ}\text{C}$	-	29.4	-	
			$T_{vj}=125^{\circ}\text{C}$	-	41.2	-	
			$T_{vj}=150^{\circ}\text{C}$	-	45.1	-	
			$T_{vj}=175^{\circ}\text{C}$	-	47.2	-	
	$E_{rr}$		$T_{vj}=25^{\circ}\text{C}$	-	18.0	-	
			$T_{vj}=125^{\circ}\text{C}$	-	38.4	-	
			$T_{vj}=150^{\circ}\text{C}$	-	45.1	-	
			$T_{vj}=175^{\circ}\text{C}$	-	52.7	-	

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

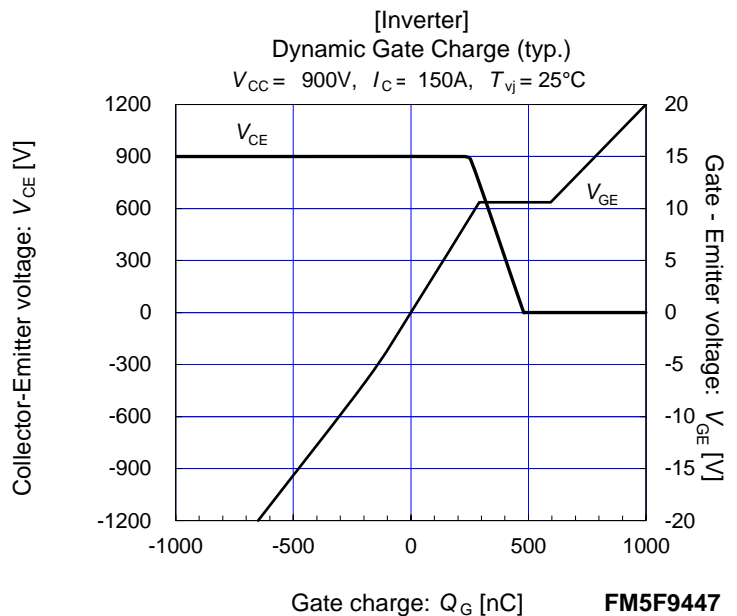
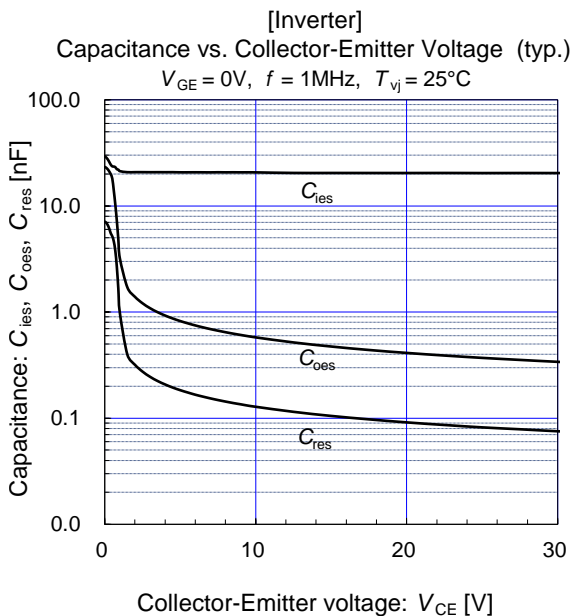
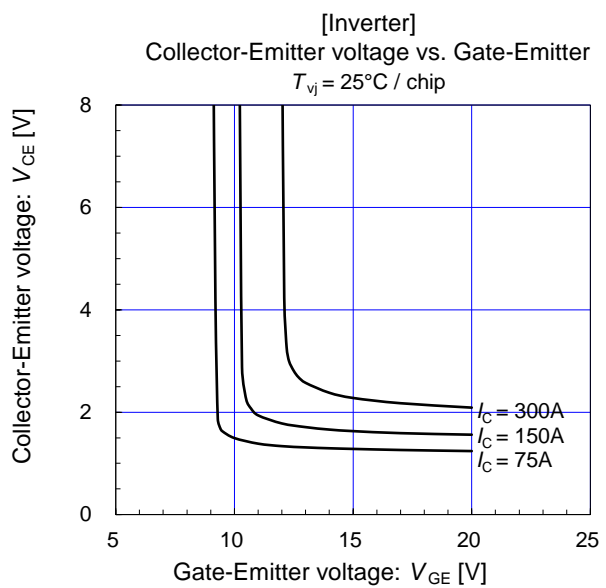
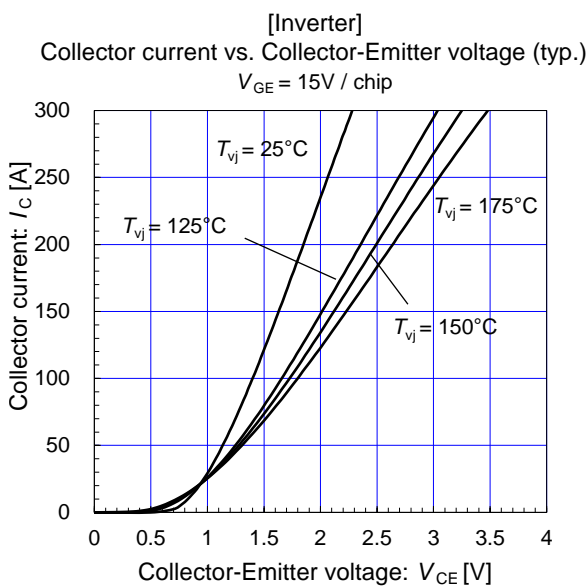
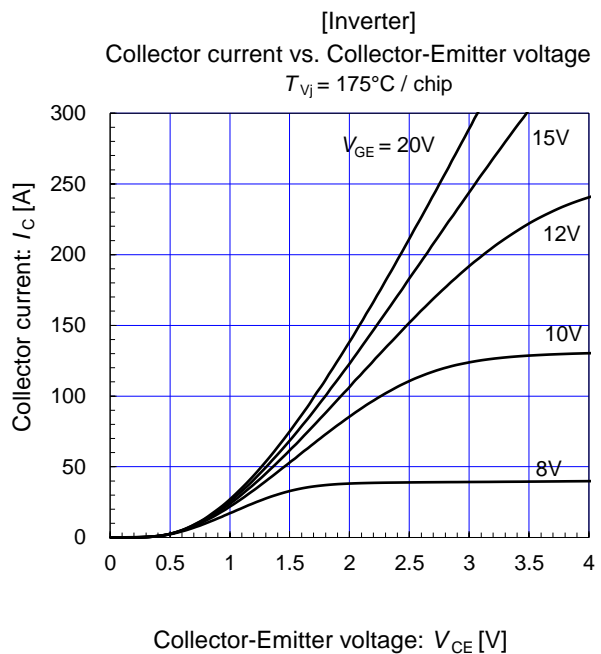
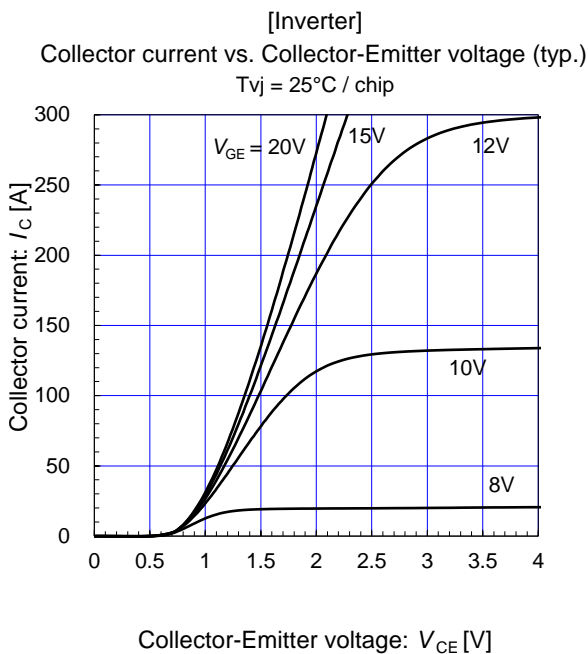
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			ns
			min.	typ.	max.	
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.162	K/W
		Inverter FWD	-	-	0.245	
Thermal resistance case to heat sink (1IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.0250	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

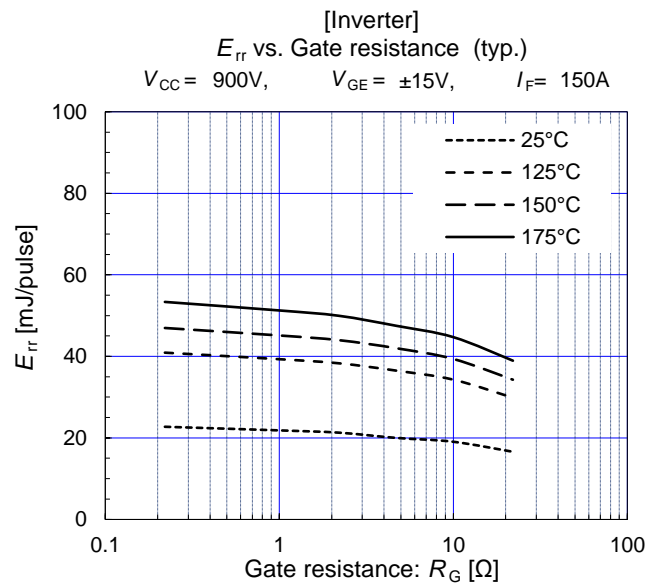
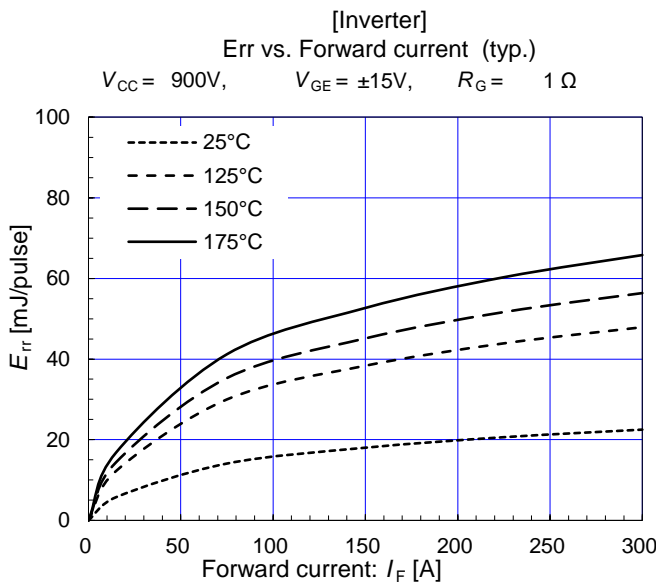
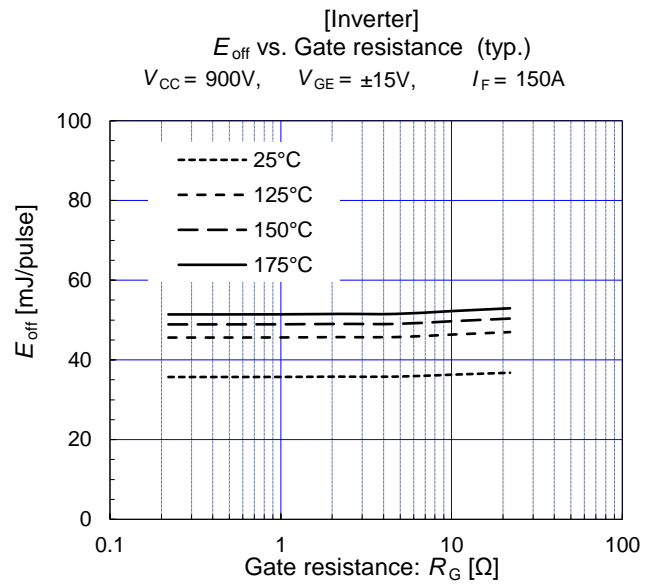
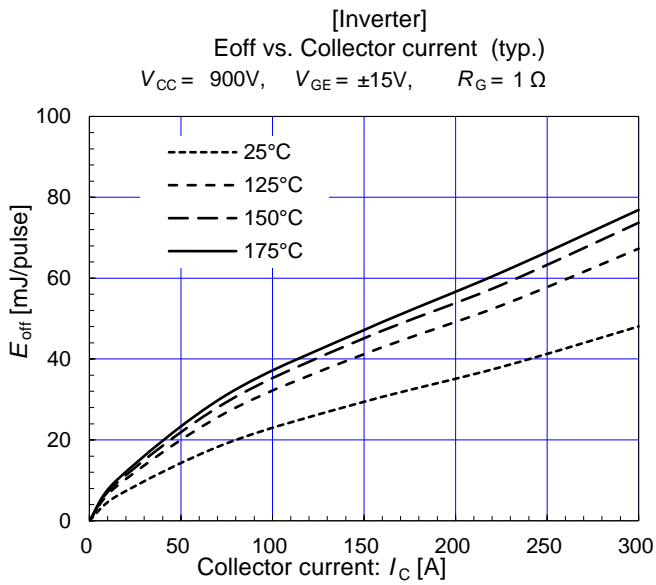
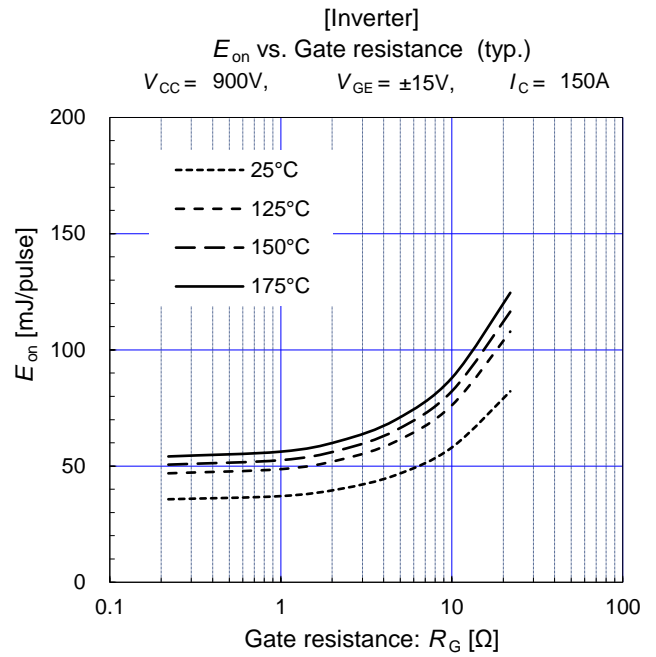
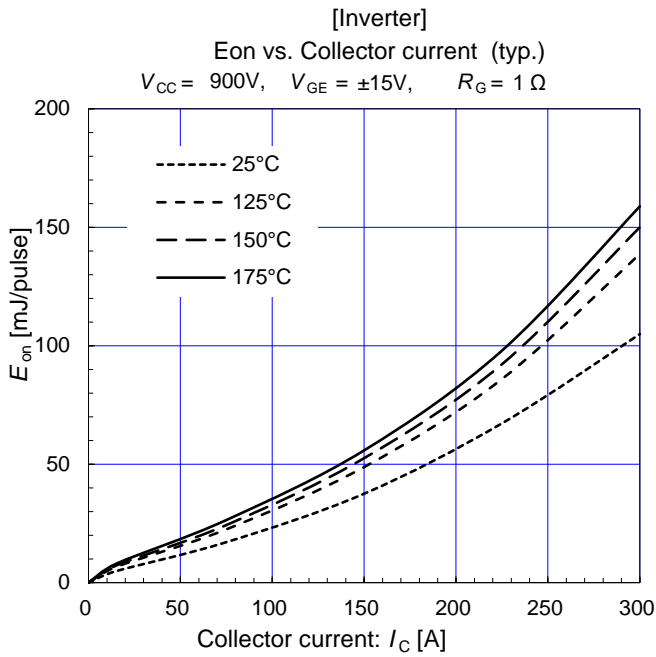
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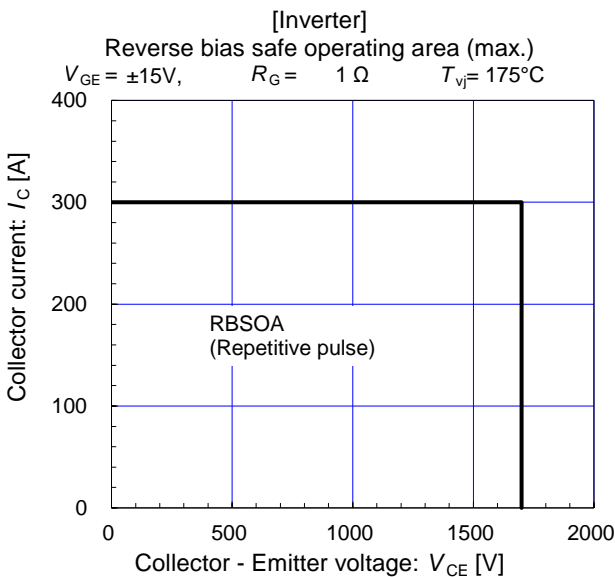
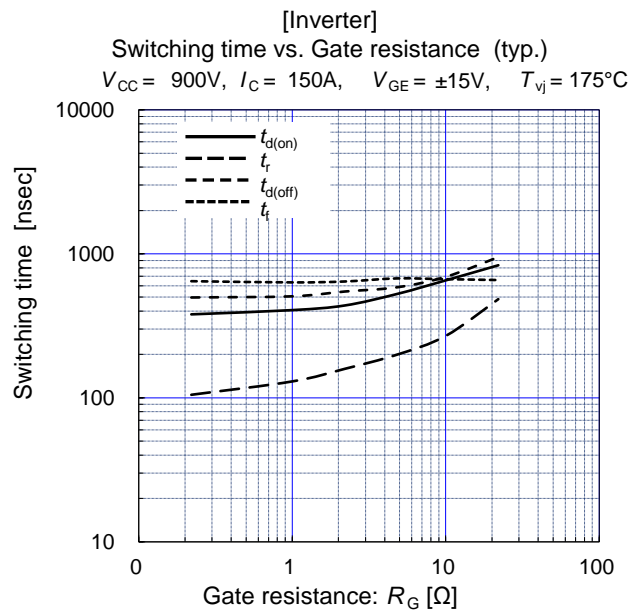
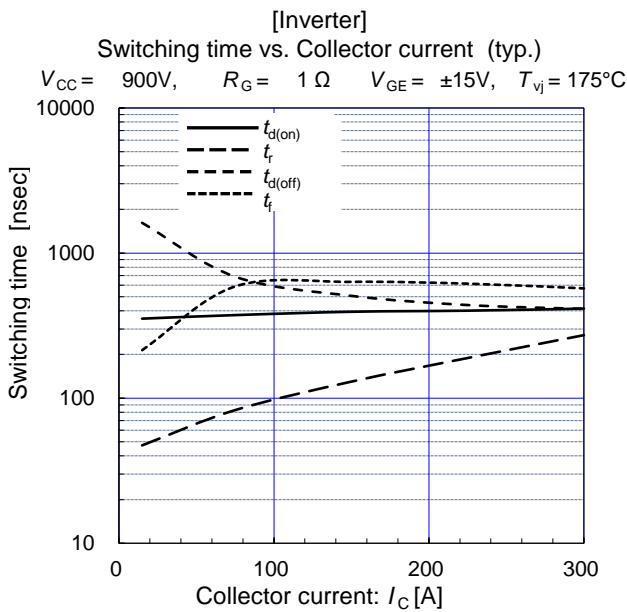
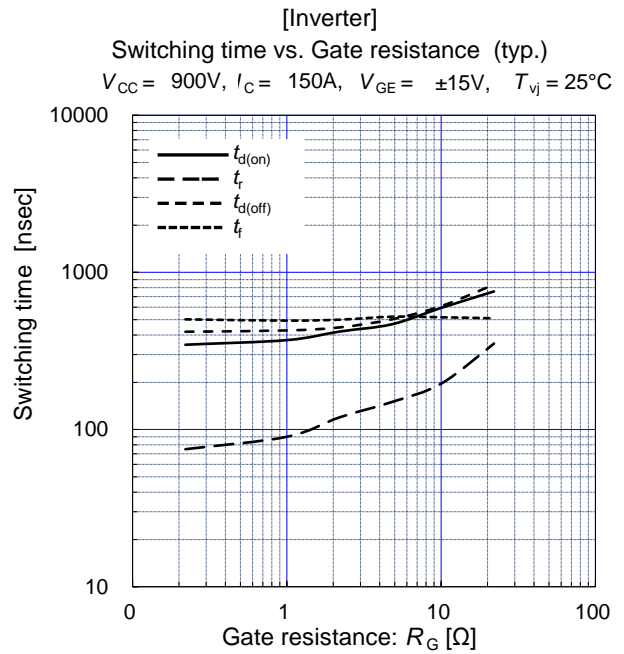
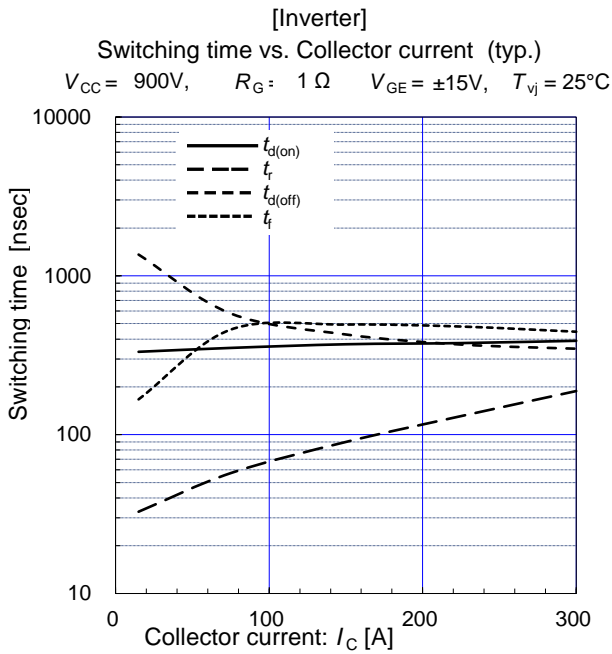
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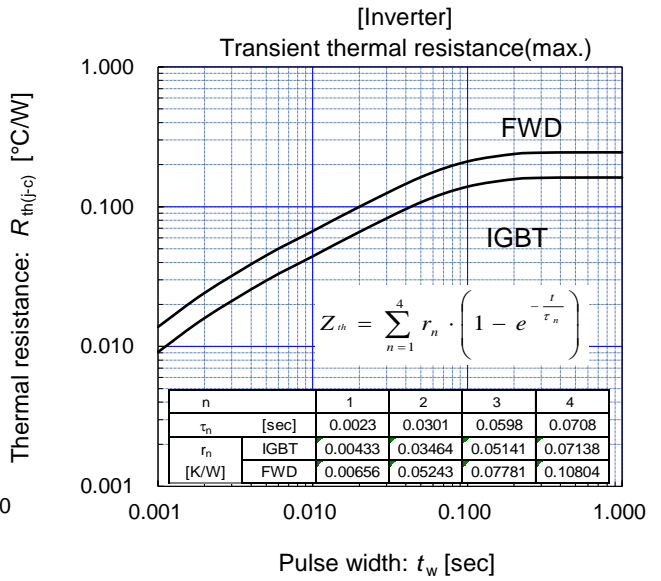
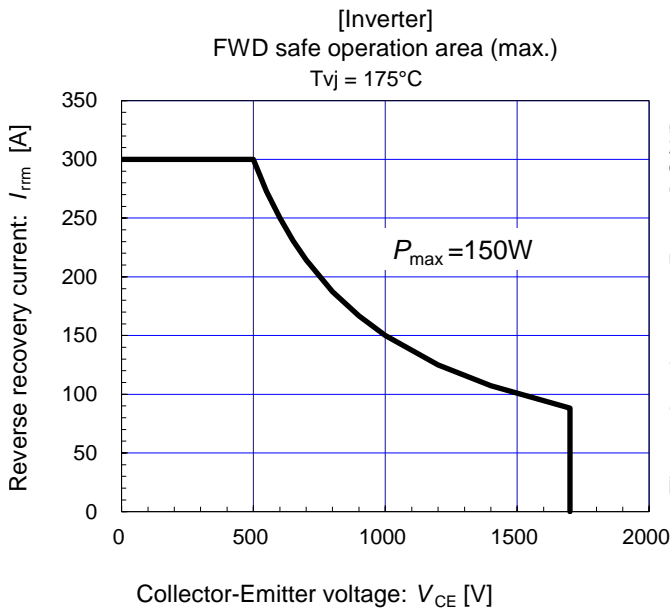
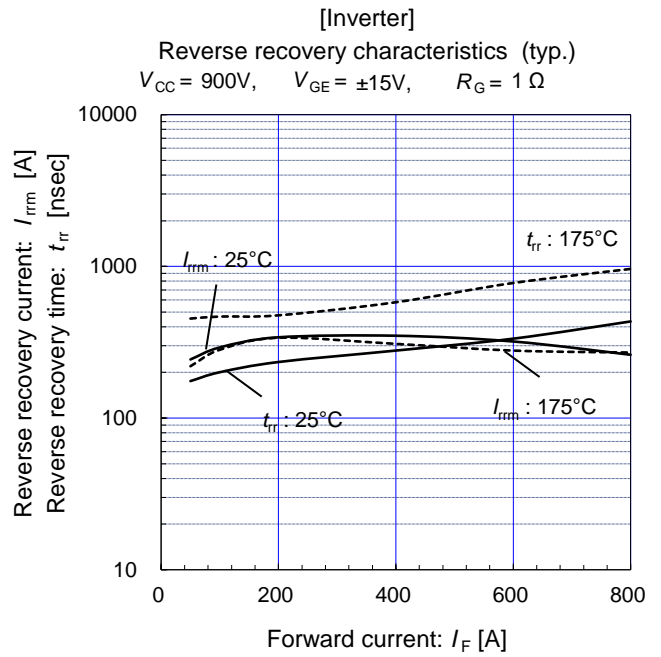
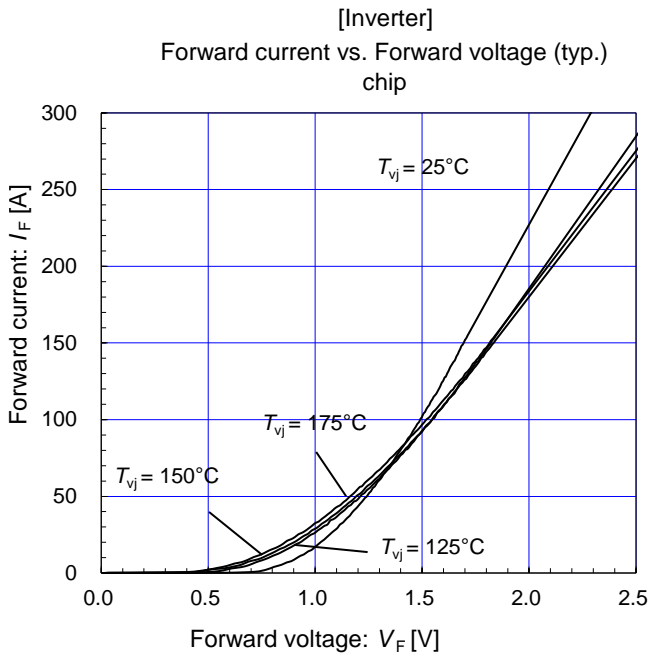
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